

High isolation dual SPDT analog switch

Features

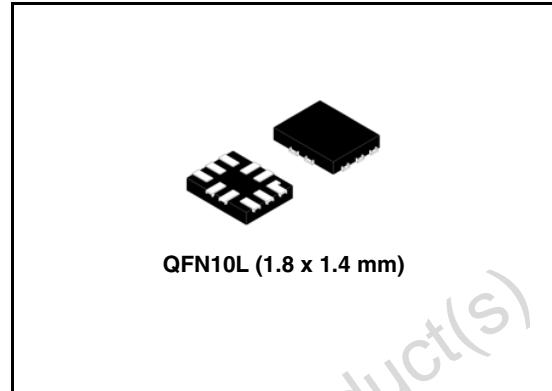
- Ultra high off-isolation:
-80 dB (typ) at 1 MHz
- Ultra low power dissipation:
 $I_{CC} = 0.2 \mu A$ (max.) at $T_A = 85^\circ C$
- R_{PEAK} on $T_n = 1.30 \Omega$ max ($T_A = 25^\circ C$)
at $V_{CC} = 4.3 V$
- R_{PEAK} on $S_n = 0.55 \Omega$ max ($T_A = 25^\circ C$)
at $V_{CC} = 4.3 V$
- Wide operating voltage range:
 V_{CC} (opr) = 1.65 to 4.3 V single supply
- 4.3 V tolerant and 1.8 V compatible threshold
on digital control input at $V_{CC} = 1.65$ to 4.3 V
- Typical bandwidth (-3 dB) at 65 MHz on S_n
channel, 58 MHz on the T_n channel
- Latch-up performance exceeds 100 mA per
JESD 78, Class II
- ESD performance exceeds JESD22
2000-V Human body model (A114-A)

Description

The STG6684 is a high-speed CMOS low voltage dual analog SPDT (single pole dual throw) switch or 2:1 multiplexer/de-multiplexer switch fabricated in silicon gate C²MOS technology.

The STG6684 is designed to operate from 1.65 to 4.3 V, making this device ideal for portable applications.

The SEL_n inputs are provided to control the switch operation. The switch S_n is ON (connected to common ports D_n) when the SEL_n input is held low and OFF (high impedance state exists between the two ports) when SEL_n is held high.



The switch T_n is “on” (connected to common port D_n) when the SEL_n input is held high and “off” (high impedance state exists between the two ports) when SEL_n is held low.

Additional key features are fast switching speed, break-before-make delay time and ultra low power consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Table 1. Device summary

| Order code | Package | Packaging |
|------------|-----------------------|---------------|
| STG6684QTR | QFN10L (1.8 x 1.4 mm) | Tape and reel |

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1 Pin settings

Figure 1. Pin connection (top through view)

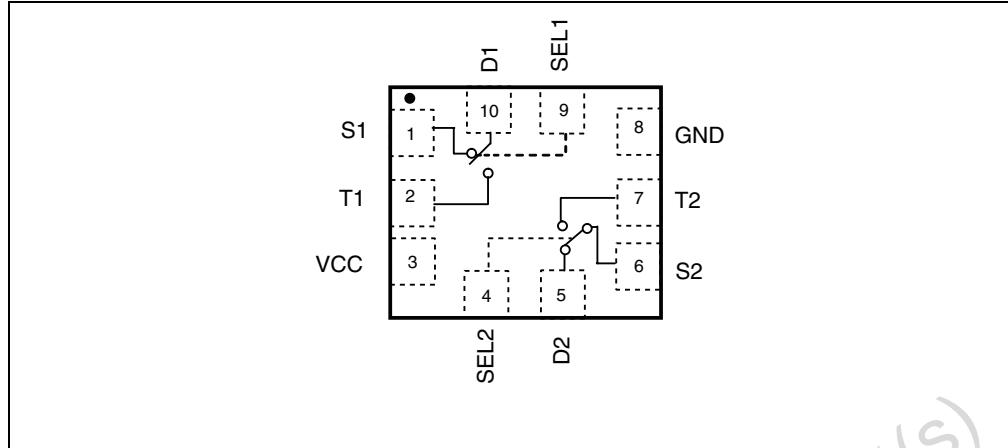


Table 2. Pin description

| Pin number | Symbol | Name and function |
|------------|-----------------|-------------------------|
| 1 | S1 | Independent channel |
| 2 | T1 | Independent channel |
| 3 | V _{CC} | Positive supply voltage |
| 4 | SEL2 | Selection control |
| 5 | D2 | Common channel |
| 6 | S2 | Independent channel |
| 7 | T2 | Independent channel |
| 8 | GND | Ground (0 V) |
| 9 | SEL1 | Selection control |
| 10 | D1 | Common channel |

2 Logic diagram

Figure 2. Logic block diagram

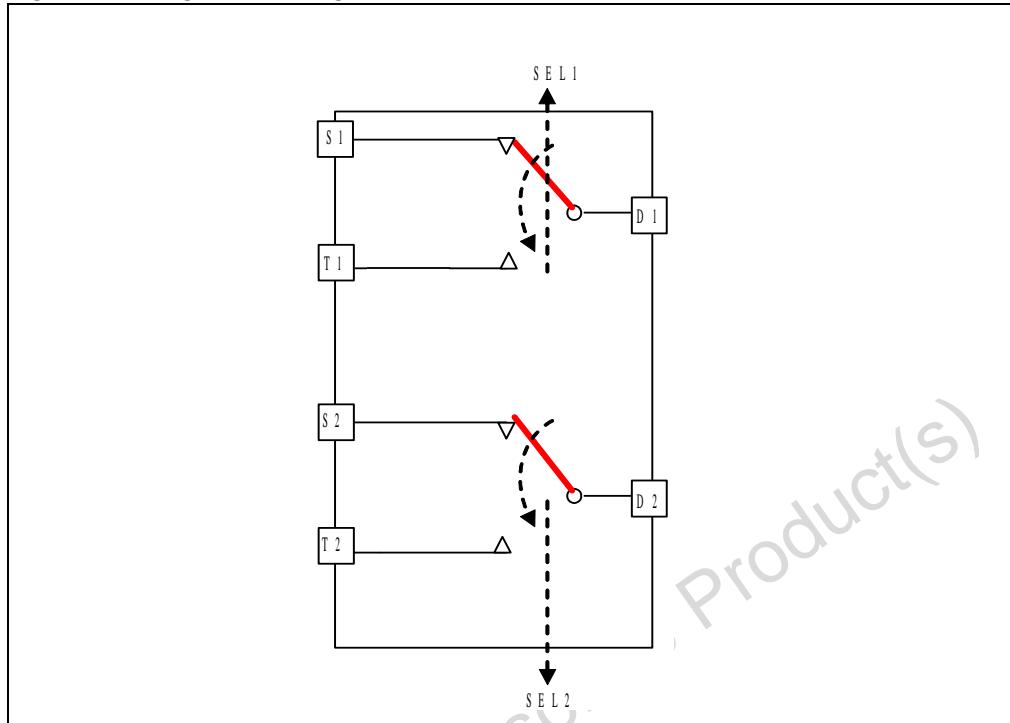


Table 3. Truth table

| SELn | Switch Sn | Switch Tn |
|------|-----------------------|-----------------------|
| L | Sn is connected to Dn | OFF ⁽¹⁾ |
| H | OFF ⁽¹⁾ | Tn is connected to Dn |

1. High impedance

3 Maximum rating

Stressing the device above the rating listed in the “Absolute maximum ratings” table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 4. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|-----------------------|--|------------------------|------|
| V_{CC} | Supply voltage | -0.5 to 5.5 | V |
| V_I | DC input voltage | -0.5 to $V_{CC} + 0.5$ | V |
| V_{IC} | DC control input voltage | -0.5 to 5.5 | V |
| V_O | DC output voltage | -0.5 to $V_{CC} + 0.5$ | V |
| I_{IKC} | DC input diode current on control pin ($V_{SEL} < 0$ V) | -50 | mA |
| I_{IK} | DC input diode current ($V_{SEL} < 0$ V) | ± 50 | mA |
| I_{OK} | DC output diode current | ± 20 | mA |
| I_O | DC output current | ± 300 | mA |
| I_{OP} | DC output current peak (pulse at 1 ms, 10% duty cycle) | ± 500 | mA |
| I_{CC} or I_{GND} | DC V_{CC} or ground current | ± 100 | mA |
| P_D | Power dissipation at $T_A=70$ °C ⁽¹⁾ | 1120 | mW |
| T_{STG} | Storage temperature | -65 to 150 | °C |
| T_L | Lead temperature (10 sec) | 300 | °C |

1. Derate above 70 °C by 18.5 mW/°C

3.1 Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Value | Unit |
|----------|--|---|---------|
| V_{CC} | Supply voltage | 1.65 to 4.3 | V |
| V_I | Input voltage | 0 to V_{CC} | V |
| V_{IC} | Control input voltage | 0 to 4.3 | V |
| V_O | Output voltage | 0 to V_{CC} | V |
| T_{op} | Operating temperature | -40 to 85 | °C |
| dt/dv | Input rise and fall time control input | $V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$ | 0 to 20 |
| | | $V_{CC} = 3.0 \text{ V to } 4.3 \text{ V}$ | 0 to 10 |
| | | | ns/V |

Obsolete Product(s) - Obsolete Product(s)

4 Electrical characteristics

Table 6. DC specifications

| Symbol | Parameter | V_{CC} (V) | Test condition | Value | | | | | Unit | |
|---------------------|---|-----------------|--|--------------------|------|------|------------------------------|------|-----------|--|
| | | | | $T_A = 25^\circ C$ | | | $-40 \text{ to } 85^\circ C$ | | | |
| | | | | Min | Typ | Max | Min | Max | | |
| V_{IH} | High level input voltage | 1.65 – 1.95 | $V_S = 0 \text{ V to } V_{CC}$ $I_S = 100 \text{ mA}$ | 0.65 V_{CC} | | | 0.65 V_{CC} | | V | |
| | | 2.3 – 2.5 | | 1.2 | | | 1.2 | | | |
| | | 2.7 – 3.0 | | 1.3 | | | 1.3 | | | |
| | | 3.3 – 3.6 | | 1.4 | | | 1.4 | | | |
| | | 4.3 | | 1.5 | | | 1.5 | | | |
| V_{IL} | Low level input voltage | 1.65 – 1.95 | $V_S = 0 \text{ V to } V_{CC}$ $I_S = 100 \text{ mA}$ | | | 0.25 | | 0.25 | V | |
| | | 2.3 – 2.5 | | | | 0.25 | | 0.25 | | |
| | | 2.7 – 3.0 | | | | 0.25 | | 0.25 | | |
| | | 3.3 – 3.6 | | | | 0.30 | | 0.30 | | |
| | | 4.3 | | | | 0.40 | | 0.40 | | |
| $R_{PEAK, Tn}$ | Switch T_n ON resistance | 4.3 | $V_S = 0 \text{ V to } V_{CC}$ $I_S = 100 \text{ mA}$ | | 1.10 | 1.3 | | 1.5 | Ω | |
| | | 3.6 | | | 1.15 | 1.4 | | 1.6 | | |
| | | 3.0 | | | 1.25 | 1.5 | | 1.8 | | |
| | | 2.7 | | | 1.35 | 1.6 | | 1.9 | | |
| | | 1.8 | | | 2.20 | 2.9 | | 3.5 | | |
| $R_{PEAK, Sn}$ | Switch S_n ON resistance | 4.3 | $V_S = 0 \text{ V to } V_{CC}$ $I_S = 100 \text{ mA}$ | | 0.45 | 0.55 | | 0.62 | Ω | |
| | | 3.6 | | | 0.48 | 0.58 | | 0.65 | | |
| | | 3.0 | | | 0.51 | 0.62 | | 0.70 | | |
| | | 2.7 | | | 0.54 | 0.70 | | 0.80 | | |
| | | 1.8 | | | 0.84 | 1.10 | | 1.30 | | |
| $\Delta R_{ON, Tn}$ | ON resistance match between T_n channels ⁽¹⁾ | 4.3 | V_S at R_{PEAK} $I_S = 100 \text{ mA}$ | | 10 | | | | $m\Omega$ | |
| | | 3.6 | | | 14 | | | | | |
| | | 3.0 | | | 14 | | | | | |
| | | 2.7 | | | 15 | | | | | |
| | | 1.8 | | | 30 | | | | | |
| $\Delta R_{ON, Sn}$ | ON resistance match between Sn channels ⁽¹⁾ | 4.3 | V_S at R_{PEAK} $I_S = 100 \text{ mA}$ | | 7 | | | | $m\Omega$ | |
| | | 3.6 | | | 7 | | | | | |
| | | 3.0 | | | 8 | | | | | |
| | | 2.7 | | | 9 | | | | | |
| | | 1.8 | | | 12 | | | | | |

Table 6. DC specifications

| Symbol | Parameter | V_{CC} (V) | Test condition | Value | | | | | Unit | |
|-----------------------|---|-----------------|--|--------------------|----------|------------|------------------------------|-----------|----------|--|
| | | | | $T_A = 25^\circ C$ | | | $-40 \text{ to } 85^\circ C$ | | | |
| | | | | Min | Typ | Max | Min | Max | | |
| R_{FLAT} , T_n | ON resistance flatness for T_n channels ⁽²⁾ | 4.3 | $V_S = 0 \text{ to } V_{CC}$ $I_S = 100 \text{ mA}$ | | 0.45 | 0.50 | | 0.55 | Ω | |
| | | 3.6 | | | 0.45 | 0.50 | | 0.55 | | |
| | | 3.0 | | | 0.50 | 0.55 | | 0.60 | | |
| | | 2.7 | | | 0.55 | 0.60 | | 0.70 | | |
| | | 1.8 | | | 1.10 | 1.70 | | 2.00 | | |
| R_{FLAT} , S_n | ON resistance flatness for S_n channels ⁽²⁾ | 4.3 | $V_S = 0 \text{ to } V_{CC}$ $I_S = 100 \text{ mA}$ | | 0.15 | 0.20 | | 0.20 | Ω | |
| | | 3.6 | | | 0.15 | 0.20 | | 0.20 | | |
| | | 3.0 | | | 0.15 | 0.20 | | 0.20 | | |
| | | 2.7 | | | 0.15 | 0.20 | | 0.20 | | |
| | | 1.8 | | | 0.35 | 0.55 | | 0.66 | | |
| I_{OFF} | OFF state leakage current (T_n , (S_n), (D_n)) | 4.3 | $V_S = 0.3 \text{ or } 4 \text{ V}$ | | | ± 0.1 | | ± 1 | μA | |
| I_{SEL} | SEL leakage current | 0 – 4.3 | $V_{SEL} = 0 \text{ to } 4.3 \text{ V}$ | | | ± 0.05 | | ± 1 | μA | |
| I_{CC} | Quiescent supply current | 1.65 – 4.3 | $V_{SEL} = V_{CC} \text{ or }$ GND | | | ± 0.05 | | ± 0.2 | μA | |
| I_{CCLV} | Quiescent supply current low voltage driving | 4.3 | $V_{SEL} = 1.65 \text{ V}$ | | ± 37 | ± 50 | | ± 100 | μA | |
| | | | $V_{SEL} = 1.80 \text{ V}$ | | ± 33 | ± 40 | | ± 50 | | |
| | | | $V_{SEL} = 2.60 \text{ V}$ | | ± 12 | ± 20 | | ± 30 | | |

- $\Delta R_{ON} = R_{ON(\max)} - R_{ON(\min)}$.
- Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Table 7. AC electrical characteristics ($C_L = 35 \text{ pF}$, $R_L = 50 \Omega$, $t_r = t_f \leq 5 \text{ ns}$)

| Symbol | Parameter | V_{CC} (V) | Test condition | Value | | | | | Unit | |
|--------------------|------------------------------|-----------------|--|--------------------------|------|-----|------------------------------------|-----|------|--|
| | | | | $T_A = 25^\circ\text{C}$ | | | $-40 \text{ to } 85^\circ\text{C}$ | | | |
| | | | | Min | Typ | Max | Min | Max | | |
| t_{PLH}, t_{PHL} | Propagation delay | 1.65 – 1.95 | $V_S = 0.8 \text{ V}$ | | 0.45 | | | | ns | |
| | | 2.3 – 2.7 | | | 0.45 | | | | | |
| | | 3.0 – 3.3 | | | 0.30 | | | | | |
| | | 3.6 – 4.3 | | | 0.30 | | | | | |
| t_{ON} | Turn-ON time | 1.65 – 1.95 | $V_S = 1.5 \text{ V}$ | | 120 | | | | ns | |
| | | 2.3 – 2.7 | | | 65 | 85 | | 90 | | |
| | | 3.0 – 3.3 | | | 42 | 55 | | 65 | | |
| | | 3.6 – 4.3 | | | 40 | 55 | | 65 | | |
| t_{OFF} | Turn-OFF time | 1.65 – 1.95 | $V_S = 0.8 \text{ V}$ | | 45 | | | | ns | |
| | | 2.3 – 2.7 | | | 18 | 30 | | 40 | | |
| | | 3.0 – 3.3 | | | 16 | 30 | | 40 | | |
| | | 3.6 – 4.3 | | | 15 | 30 | | 40 | | |
| t_D | Break-before-make time delay | 1.65 – 1.95 | $C_L = 35 \text{ pF}$ $R_L = 50 \Omega$ $V_S = 1.5 \text{ V}$ | 2 | 18 | | | | ns | |
| | | 2.3 – 2.7 | | 2 | 10 | | | | | |
| | | 3.0 – 3.3 | | 2 | 8 | | | | | |
| | | 3.6 – 4.3 | | 2 | 6 | | | | | |
| Q | Charge injection | 1.65 – 1.95 | $C_L = 100 \text{ pF}$ $R_L = 1 \text{ M}\Omega$ $V_{GEN} = 0 \text{ V}$ $R_{GEN} = 0 \Omega$ | | 43 | | | | pC | |
| | | 2.3 – 2.7 | | | 51 | | | | | |
| | | 3.0 – 3.3 | | | 51 | | | | | |
| | | 3.6 – 4.3 | | | 49 | | | | | |

Table 8. Analog switch characteristics ($C_L = 5 \text{ pF}$, $R_L = 50 \Omega$, $T_A = 25^\circ\text{C}$)

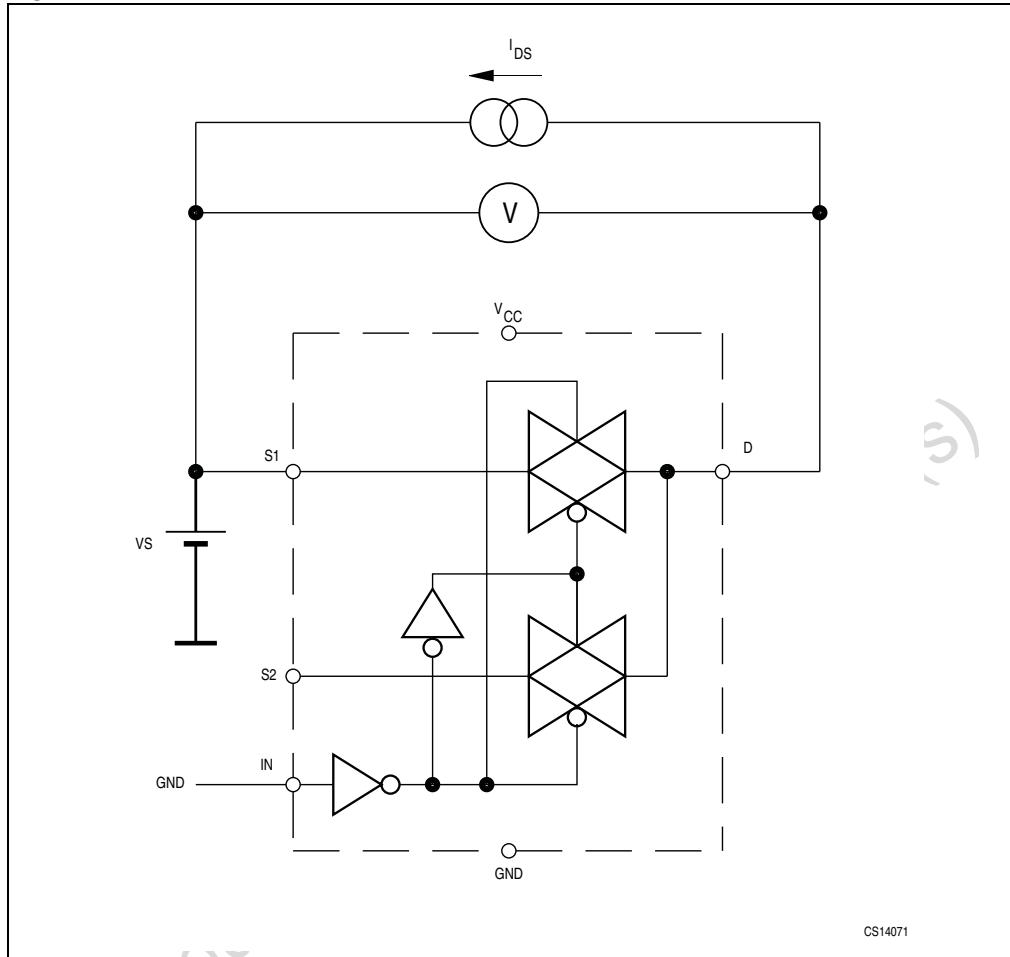
| Symbol | Parameter | V_{CC} (V) | Test condition | Value | | | | | Unit | |
|---------------------|--|-----------------|---|--------------------------|------|-----|------------------------------------|-----|------|--|
| | | | | $T_A = 25^\circ\text{C}$ | | | $-40 \text{ to } 85^\circ\text{C}$ | | | |
| | | | | Min | Typ | Max | Min | Max | | |
| OIRR _{Tn} | Off isolation for switch T1,T2 | 1.65 – 4.3 | $V_S=1 \text{ V}_{\text{RMS}}$, $f=1 \text{ MHz}$, $R_L = 50 \Omega$ | | -80 | | | | dB | |
| | | | $V_S=1 \text{ V}_{\text{RMS}}$, $f = 10 \text{ MHz}$, $R_L = 50 \Omega$ | | -60 | | | | | |
| OIRR _{Sn} | Off isolation for switch S1, S2 | 1.65 – 4.3 | $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 100 \text{ kHz}$ $R_L = 50 \Omega$ | | -66 | | | | dB | |
| | | | $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 1 \text{ MHz}$ $R_L = 50 \Omega$ | | -45 | | | | | |
| Xtalk _{Sn} | Crosstalk between S1 and S2 | 1.65 – 4.3 | $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 1 \text{ MHz}$ Signal = 0 dBm | | -90 | | | | dB | |
| | | | $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 10 \text{ MHz}$ Signal = 0 dBm | | -69 | | | | | |
| Xtalk _{Tn} | Crosstalk between T1 and T2 | 1.65 – 4.3 | $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 1 \text{ MHz}$ Signal = 0 dBm | | -85 | | | | dB | |
| | | | $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 10 \text{ MHz}$ Signal = 0 dBm | | -74 | | | | | |
| THD _{Sn} | Total harmonic distortion | 2.3 – 4.3 | $f = 20 \text{ Hz to } 20$ kHz $R_L = 600 \Omega$ $C_L = 50 \text{ pF}$ $V_{IN} = 2 \text{ V}_{\text{P-P}}$ $V_{DC} = V_{CC}/2$ | | 0.01 | | | | % | |
| BW _{Tn} | -3dB bandwidth for switch T1, T2 | 1.65 – 4.3 | $R_L = 50 \Omega$ Signal = 0 dBm | | 58 | | | | MHz | |
| BW _{Sn} | -3dB bandwidth for switch S1,S2 | 1.65 – 4.3 | $R_L = 50 \Omega$ Signal = 0 dBm | | 65 | | | | MHz | |

| Symbol | Parameter | V_{CC} (V) | Test condition | Value | | | | | Unit | |
|--------------|---|-----------------|------------------------|-----------------------------------|-----|-----|------------------------------------|-----|------|--|
| | | | | $T_A = 25 \text{ }^\circ\text{C}$ | | | -40 to 85 $\text{ }^\circ\text{C}$ | | | |
| | | | | Min | Typ | Max | Min | Max | | |
| C_{SEL} | Control pin input capacitance | | $V_{CC} = 0 \text{ V}$ | | 9 | | | | | |
| $C_{ON,Tn}$ | Tn port capacitance when the switch is enabled | 3.3 | $f = 1 \text{ MHz}$ | | 113 | | | | | |
| $C_{ON,Sn}$ | Sn port capacitance when the switch is enabled | 3.3 | $f = 1 \text{ MHz}$ | | 88 | | | | pF | |
| $C_{OFF,Tn}$ | Tn port capacitance when the switch is disabled | 3.3 | $f = 1 \text{ MHz}$ | | 85 | | | | | |
| $C_{OFF,Sn}$ | Sn port capacitance when the switch is disabled | 3.3 | $f = 1 \text{ MHz}$ | | 40 | | | | | |

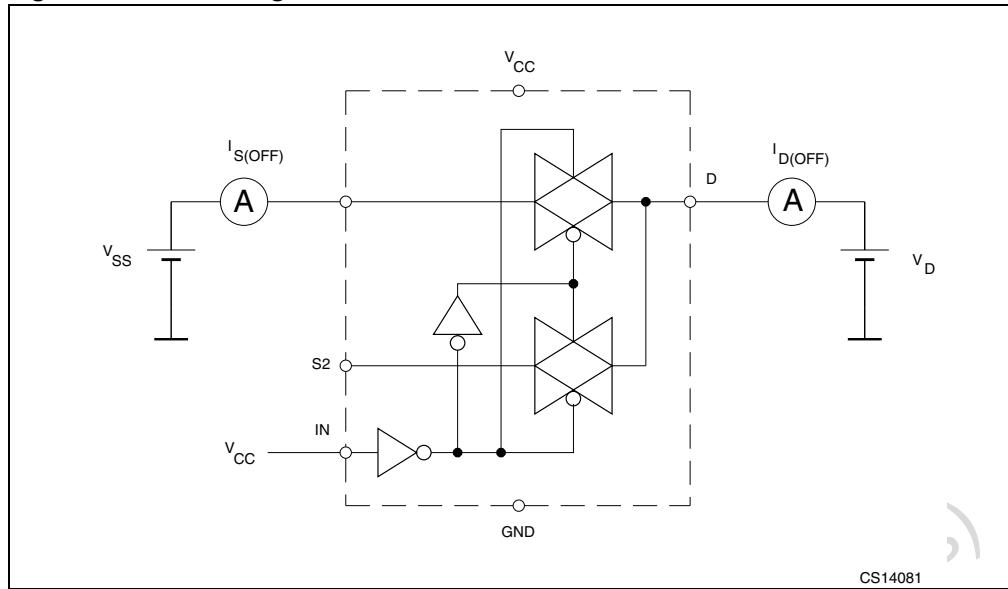
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5 Test circuit

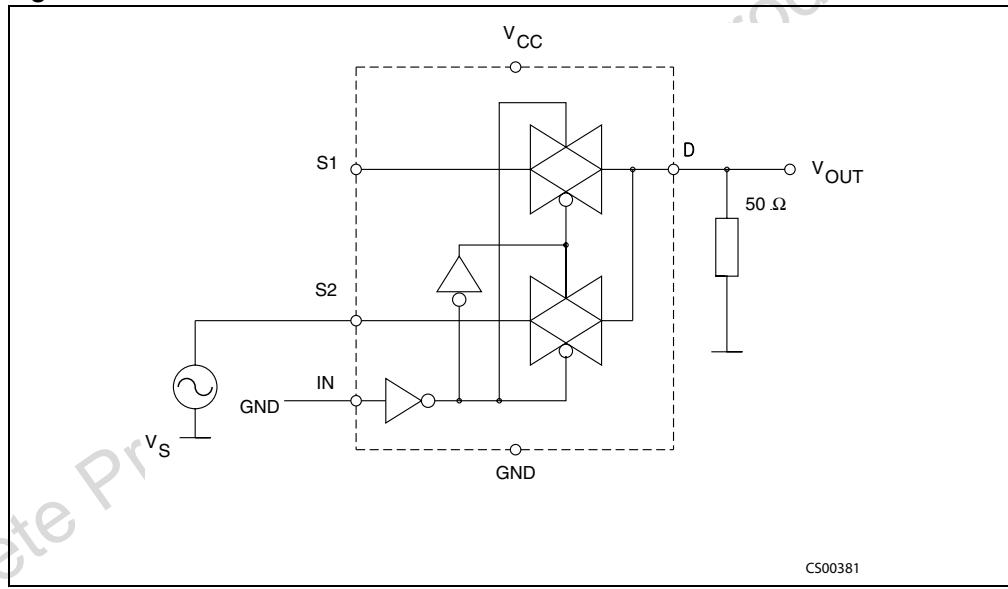
Figure 3. ON resistance



CS14071

Figure 4. OFF leakage

CS14081

Figure 5. OFF isolation

CS00381

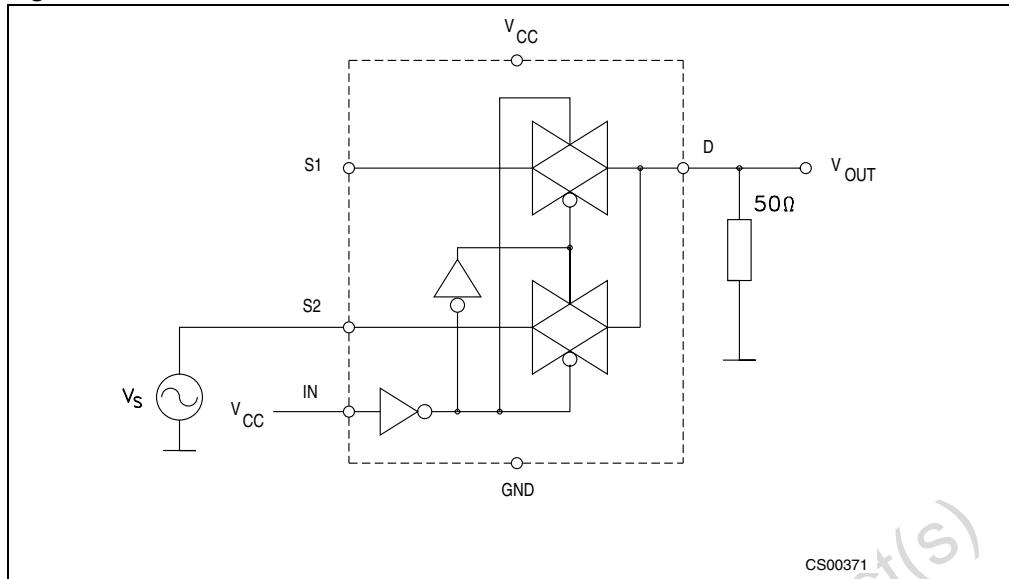
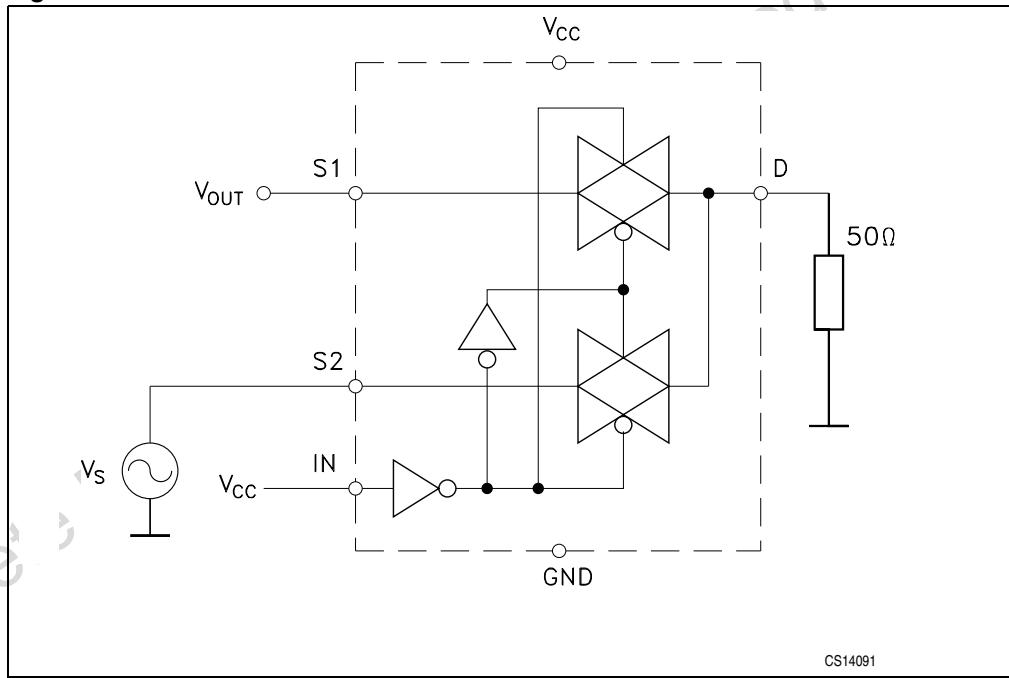
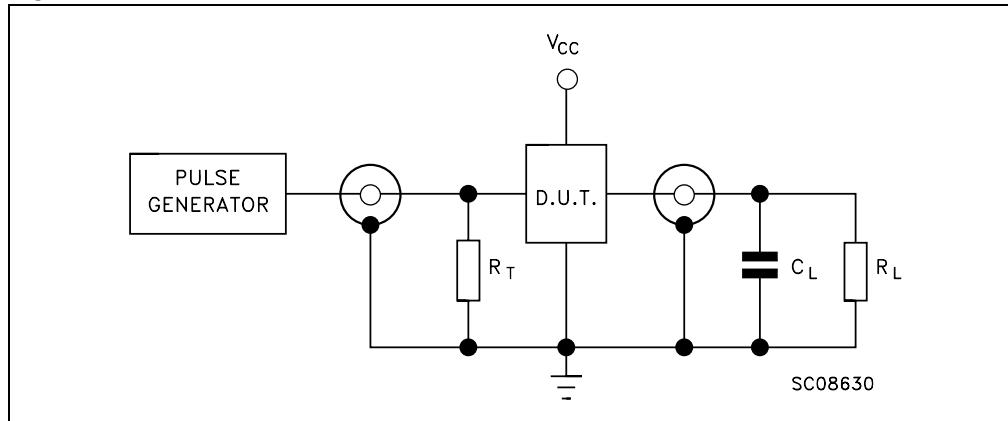
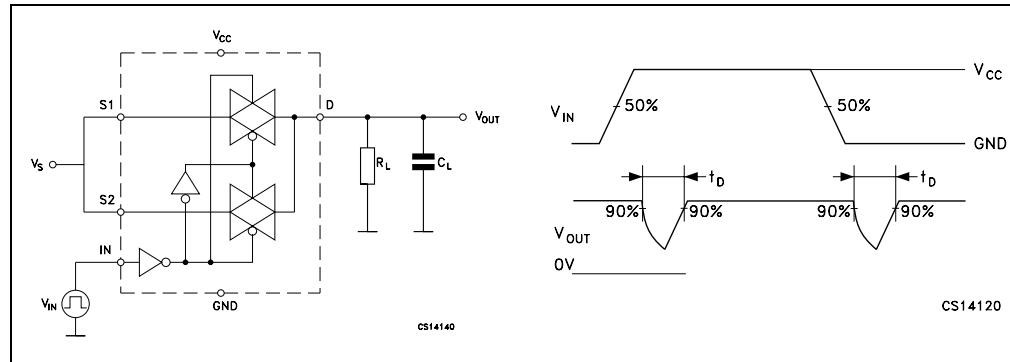
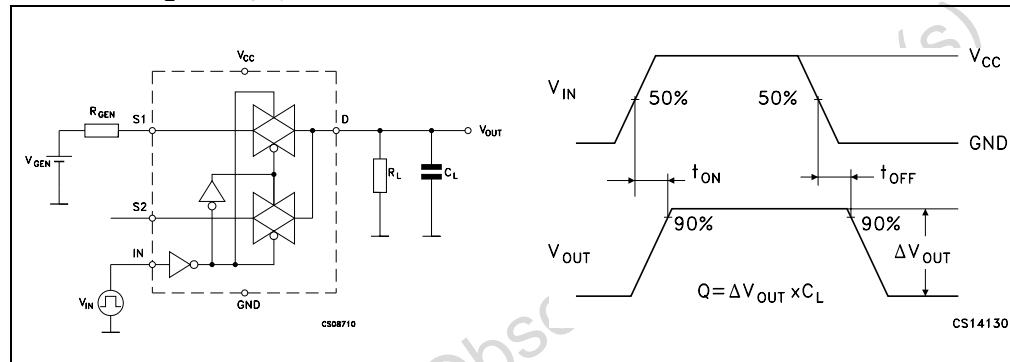
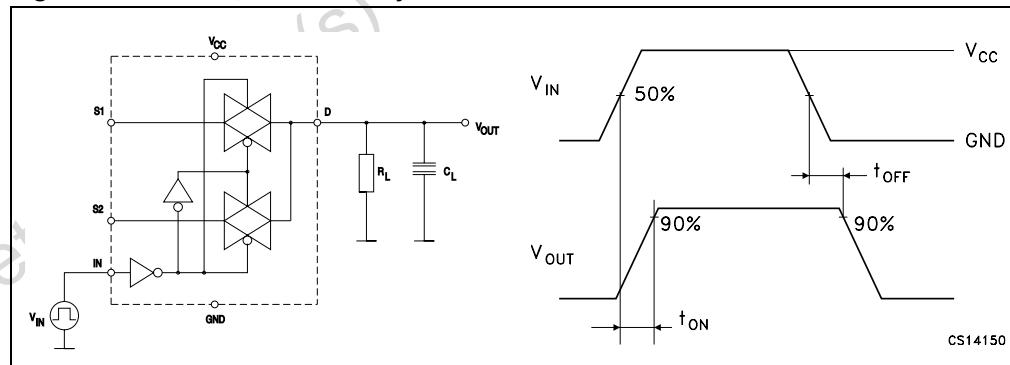
Figure 6. Bandwidth**Figure 7. Switch-to-switch crosstalk**

Figure 8. Test circuit

1. $C_L = 5/35 \text{ pF}$ or equivalent (includes jig and probe capacitance)
2. $R_L = 50 \Omega$ or equivalent
3. $R_T = Z_{\text{OUT}}$ of pulse generator (typically 50Ω)

Obsolete Product(s) - Obsolete Product(s)

Figure 9. Break-before-make time delay**Figure 10. Switching time and charge injection ($V_{GEN} = 0$, $R_{GEN} = 0 \Omega$, $R_L = 1 M\Omega$, $C_L = 100 pF$)****Figure 11. Turn on, turn off delay time**

6 Application diagram

Figure 12. Application diagram

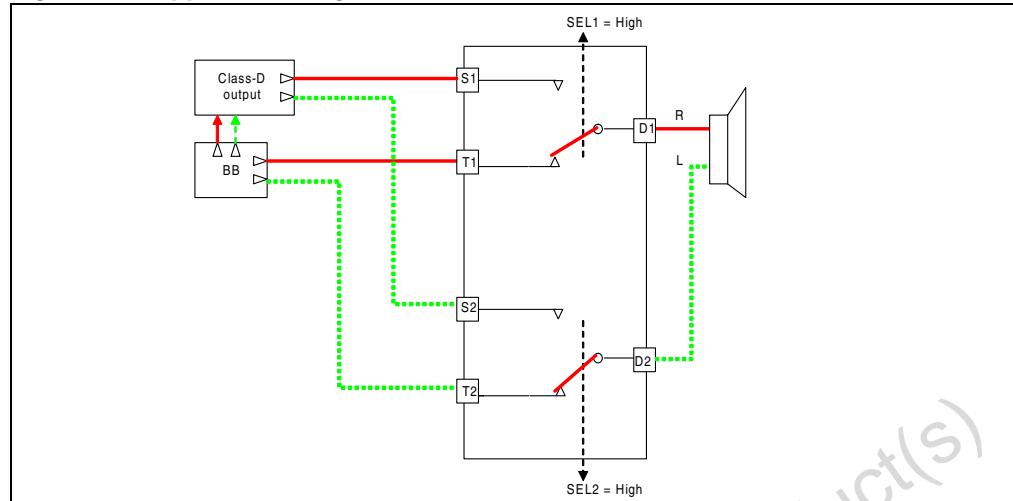
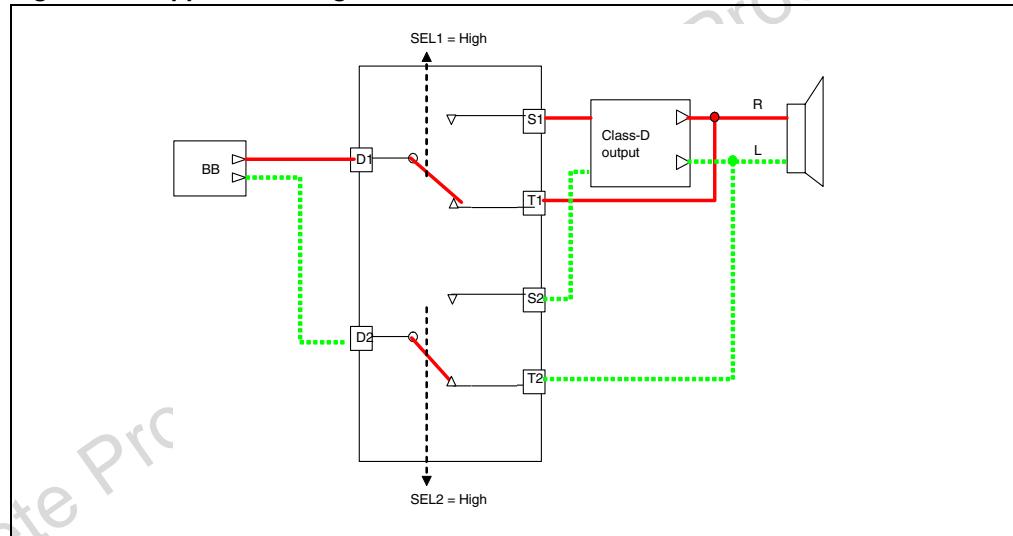


Figure 13. Application diagram



7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Figure 14. QFN10L (1.8 x 1.4 mm) package outline

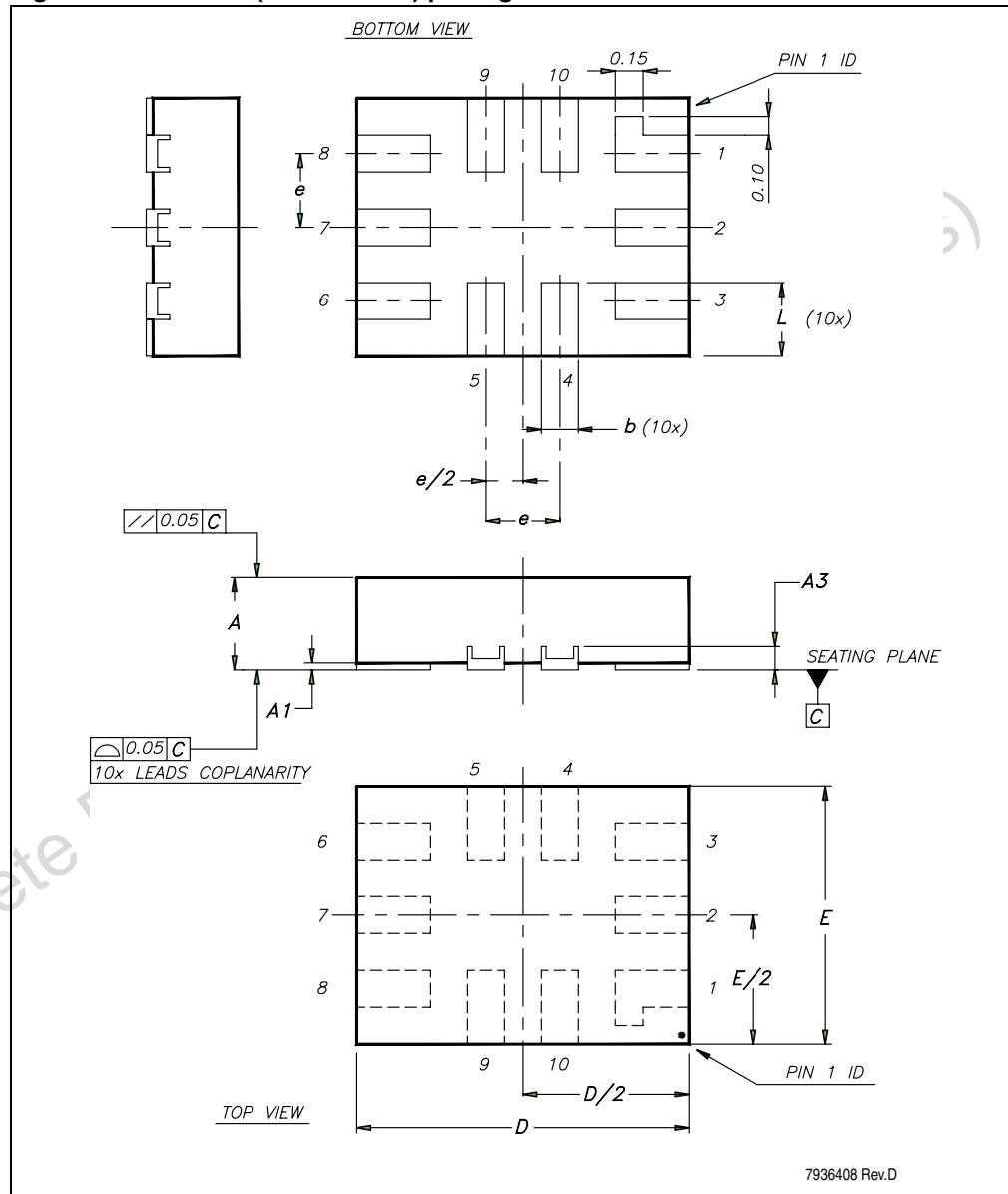
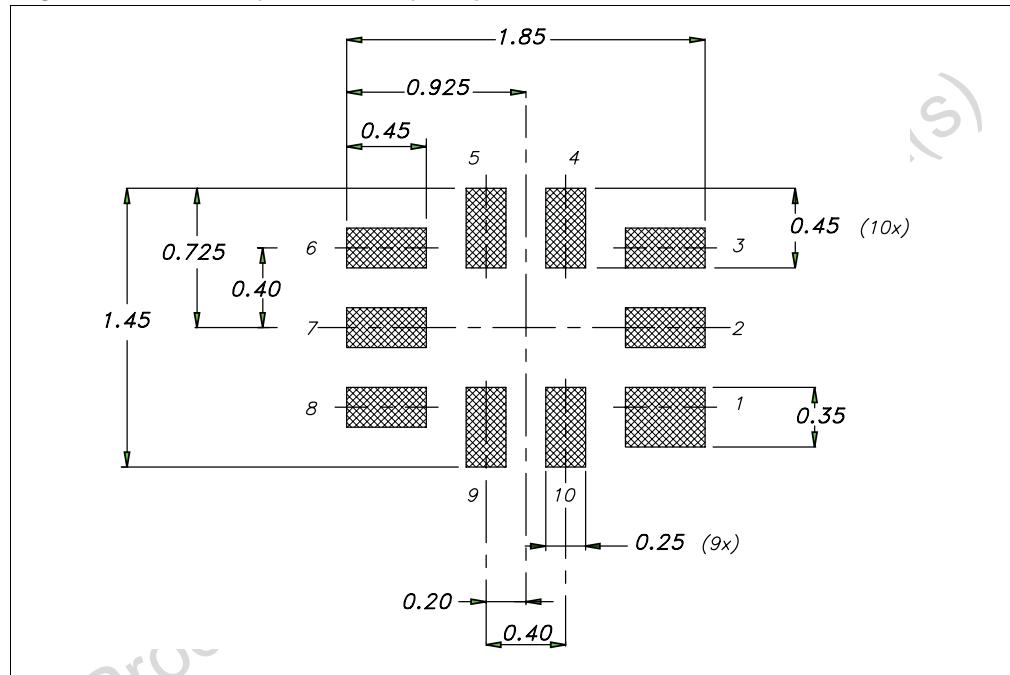


Table 2. QFN10L(1.8 x 1.4 mm) mechanical data

| Symbol | Millimeters | | |
|--------|-------------|-------|------|
| | Min | Typ | Max |
| A | 0.45 | 0.50 | 0.55 |
| A1 | 0 | 0.02 | 0.05 |
| A3 | | 0.127 | |
| b | 0.15 | 0.20 | 0.25 |
| D | 1.75 | 1.80 | 1.85 |
| E | 1.35 | 1.40 | 1.45 |
| e | | 0.40 | |
| L | 0.35 | 0.40 | 0.45 |

Figure 15. QFN10L (1.8 x 1.4 mm) footprint recommendations

Obsolete Proc~

Figure 16. QFN10L (1.8 x 1.4 mm) carrier tape

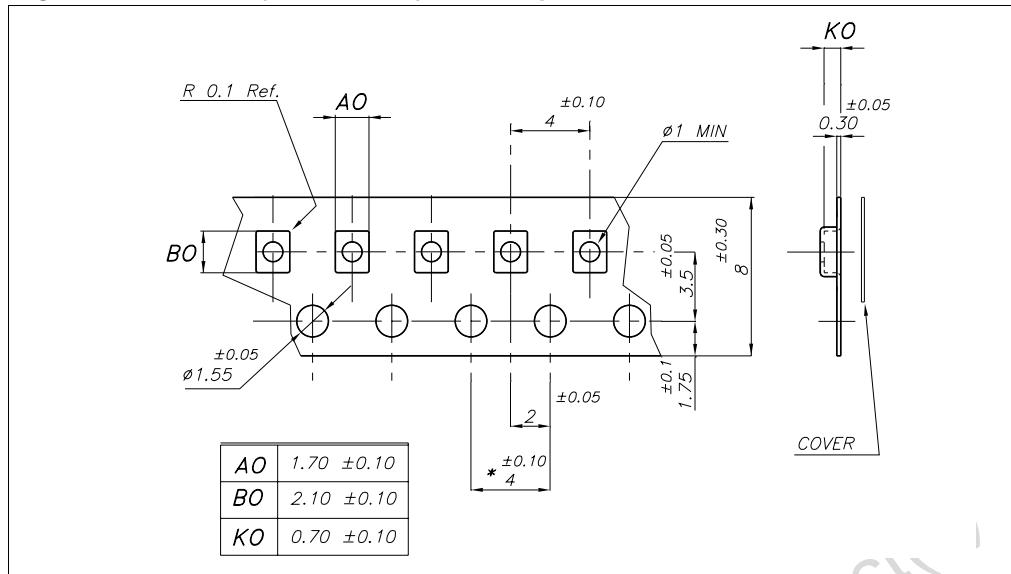


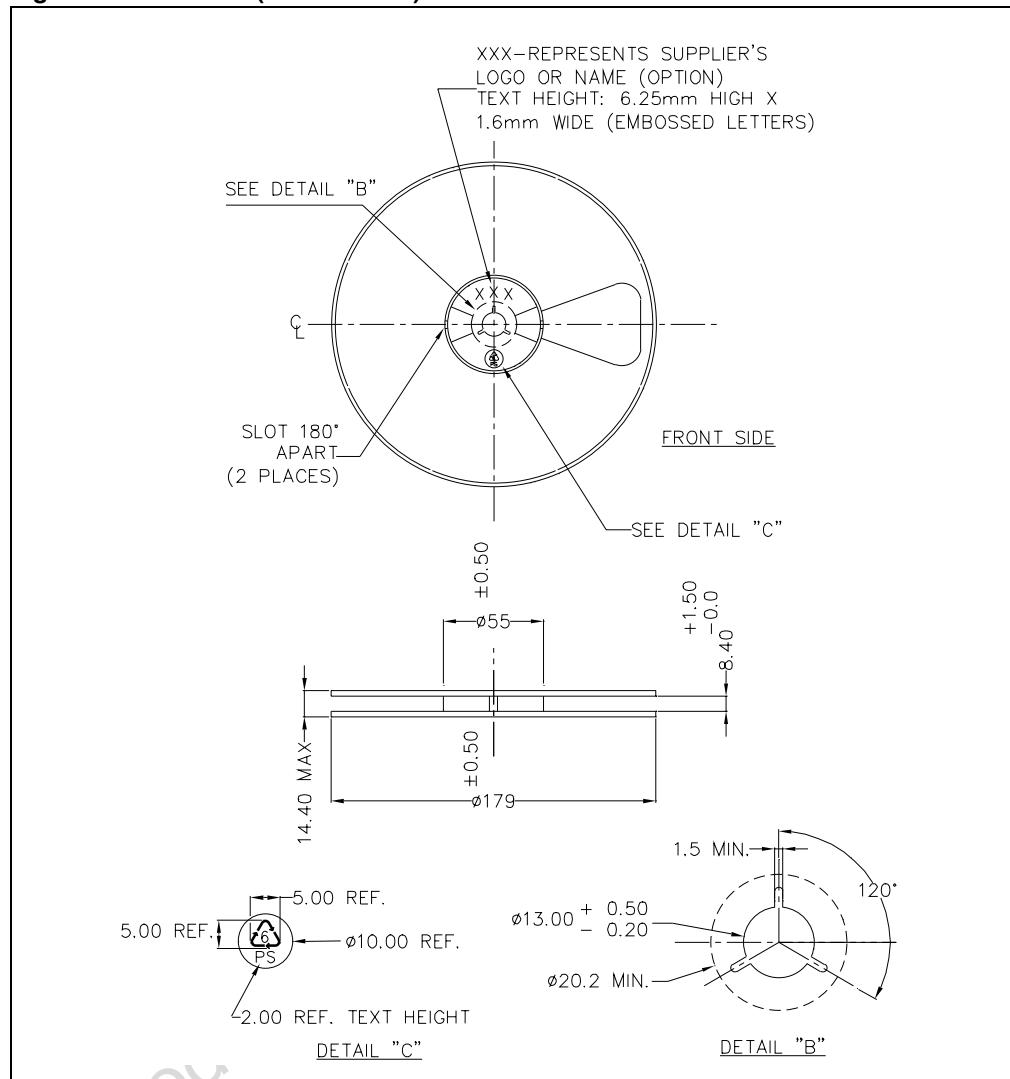
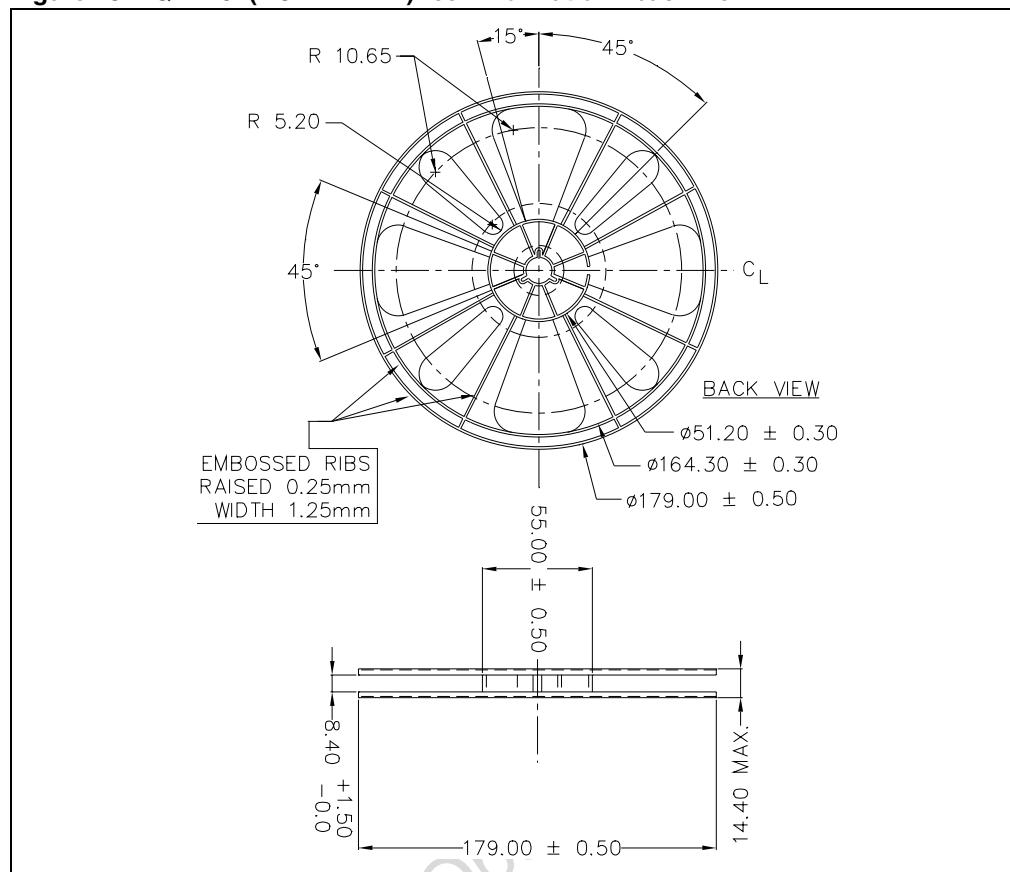
Figure 17. QFN10L (1.8 x 1.4 mm) reel information - front side

Figure 18. QFN10L(1.8 x 1.4 mm) reel information - back view

8 Revision history

Table 9. Document revision history

| Date | Revision | Changes |
|------------|----------|------------------|
| 9-Jan-2008 | 1 | Initial release. |

Obsolete Product(s) - Obsolete Product(s)



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